

# Interpreting Manufacturing Variance using a Data Mining Approach



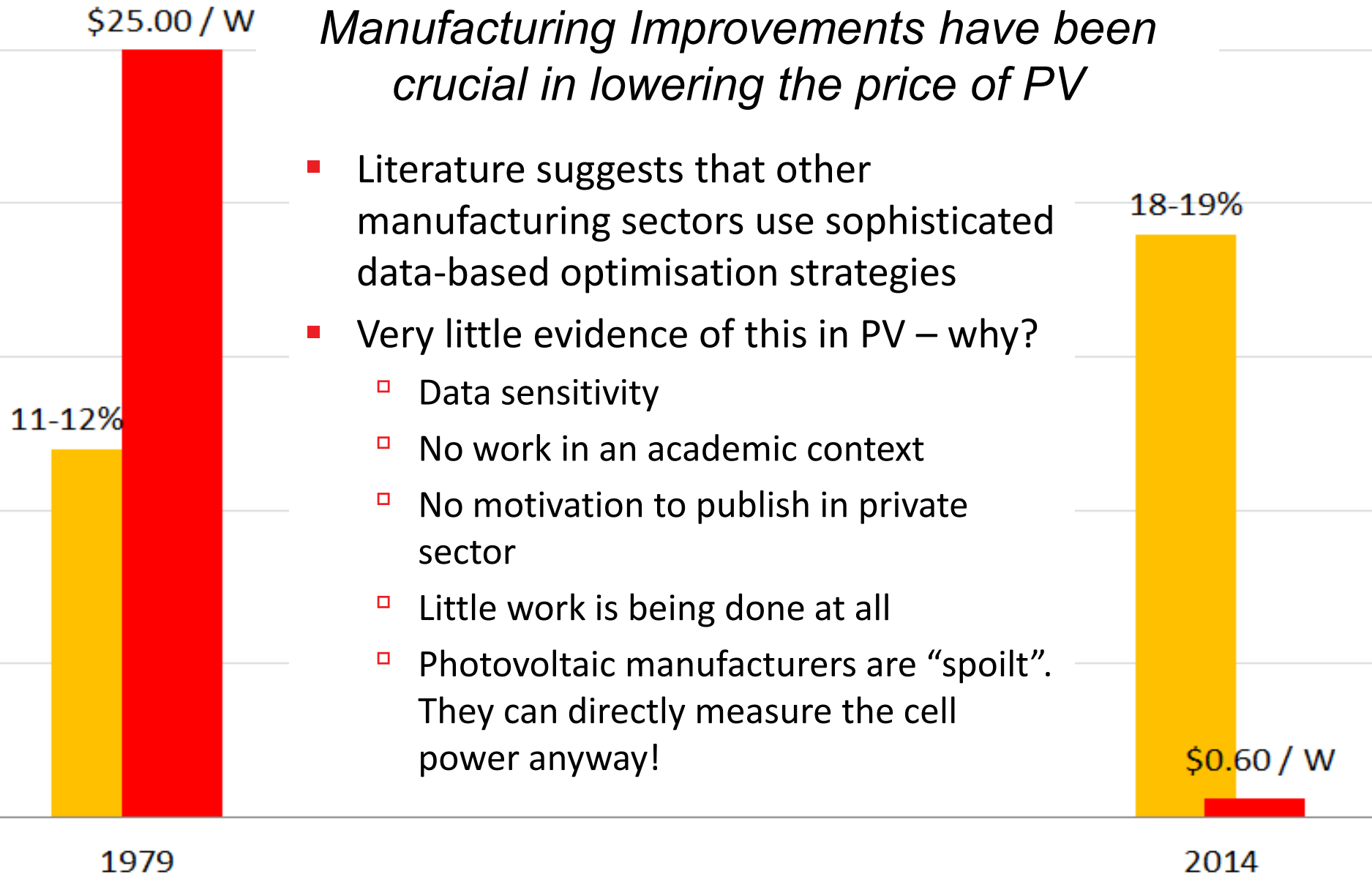
Oct 2014



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# Why Manufacturing Research?



## Materials

1. Data from mc-Si cells from Suntech in Wuxi, China, 2013
2. Typical performance parameters for 20,000 cells
3. Data from two lines with different screen print patterns.

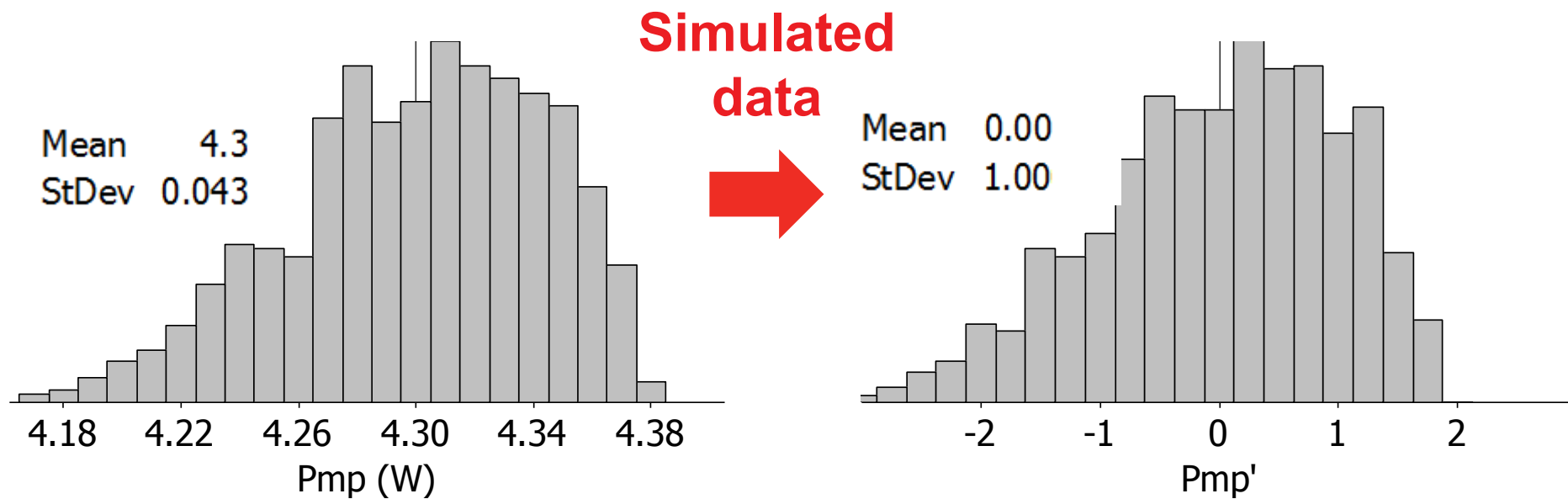
## Methods

1. Data Normalisation
2. Simple data mining / data manipulation
3. Data Rotation to isolate variance

## Aim

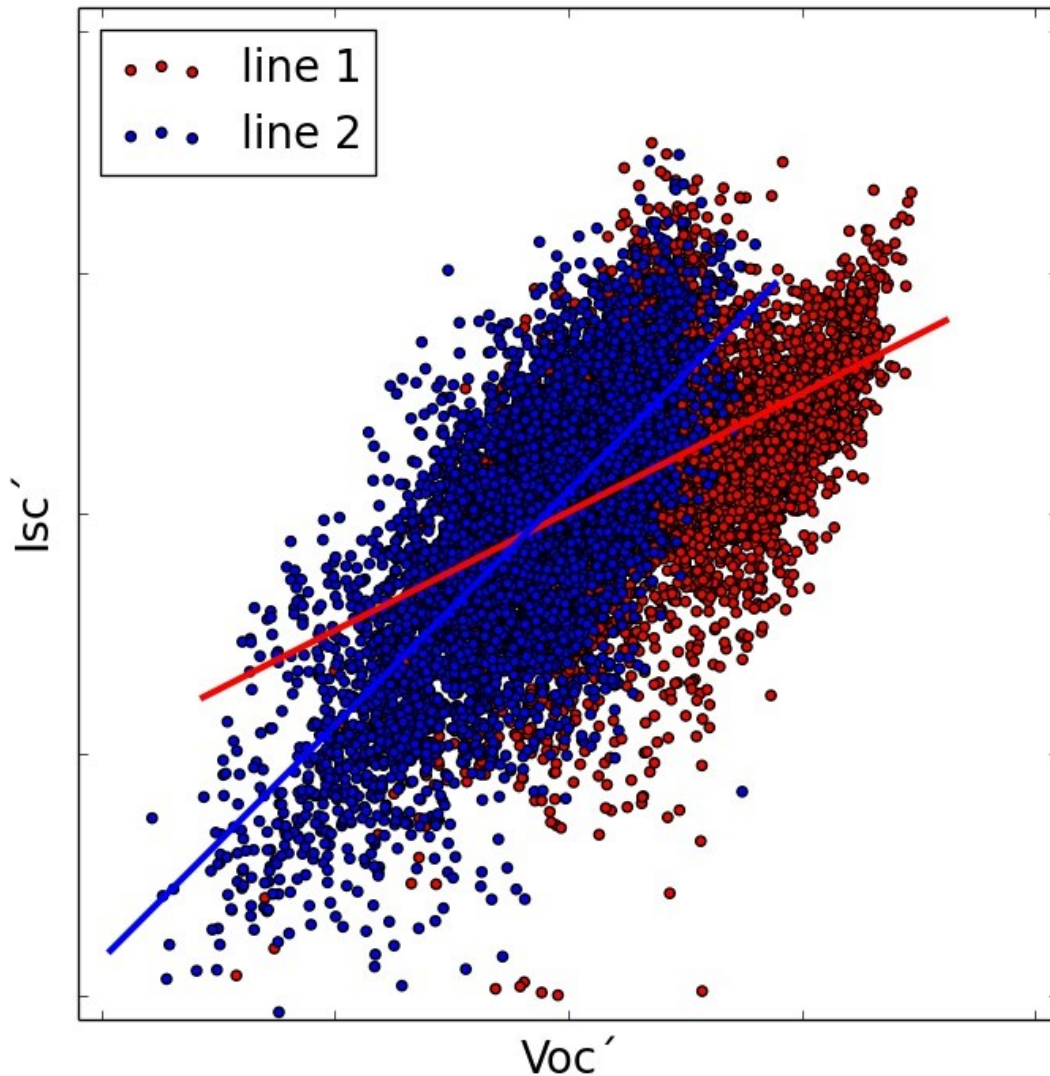
1. Demonstration of statistical techniques
2. Improved understanding of production variance
3. Improved understanding of cell operation

- All data must be normalised to share it publically
- Data normalisation most often means **Mean 0, Variance 1**



- Here, variance in FF, Voc and Isc is scaled **relative** to Pmp
  - E.g  $0.043/4.3 = 1\%$  would be considered 1 unit of variance in Voc, Isc and FF.

# Isc vs Voc data

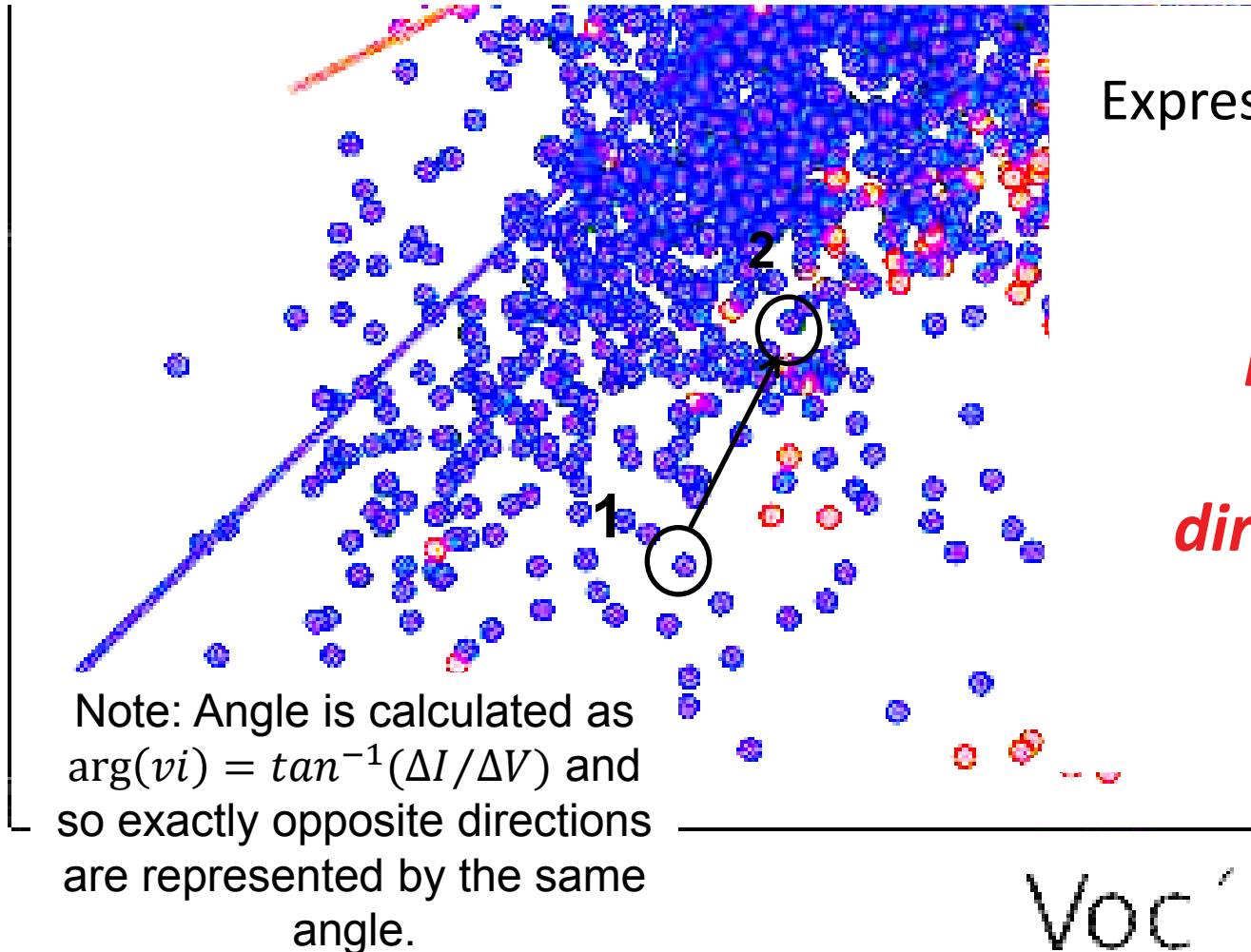


Data is from

**20,000 cells**

There is a different  $I_{sc}'$  vs  $V_{oc}'$  trend in both data sets with a different line of best fit.

1. Consider some point on this relationship in time
2. Look at what changes to make the next cell



Express this change as a

**vector  $\vec{vi}$ ,**

with

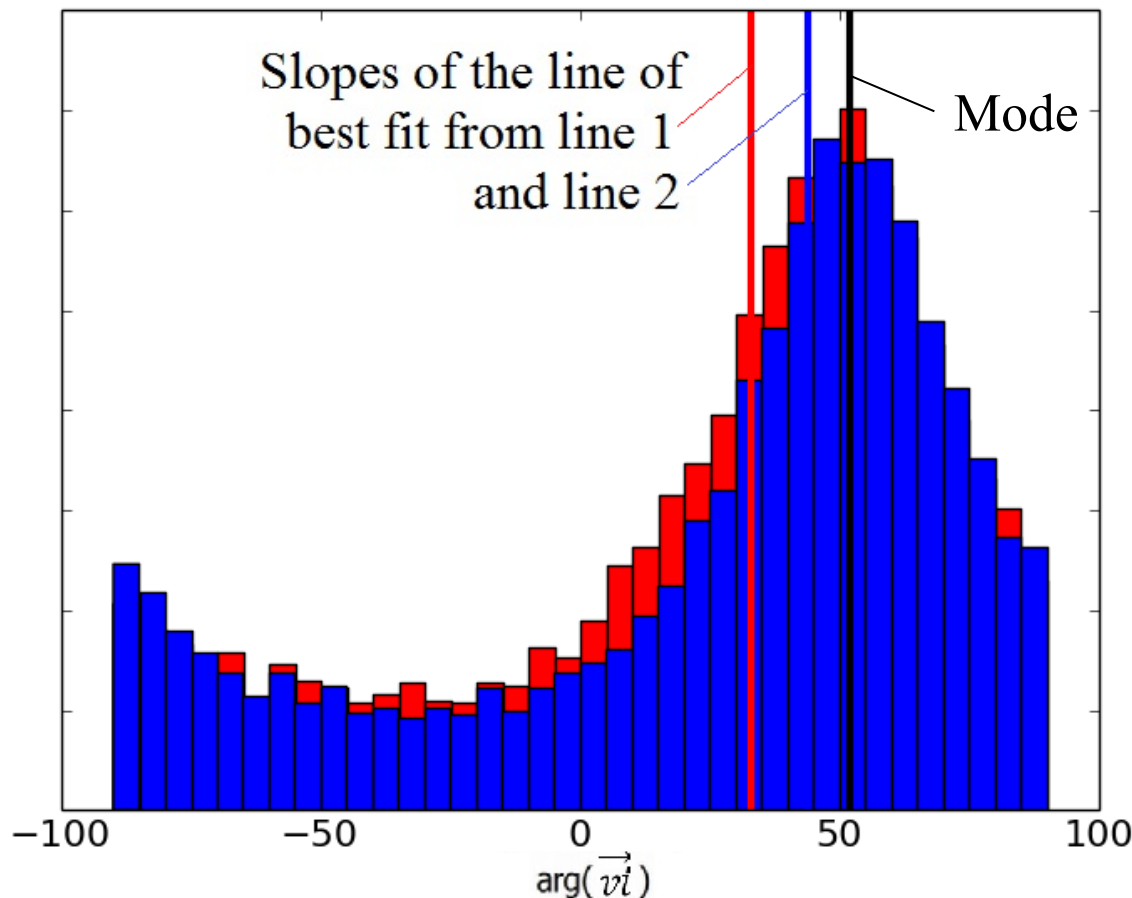
**length  $|\vec{vi}|$**

and

**direction  $\arg(\vec{vi})$**

## Isc vs Voc data

- Plot the histogram of the direction angle of this vector
- The modal response is  $52^\circ$  in both cases
- The lines of best fit have lower slope

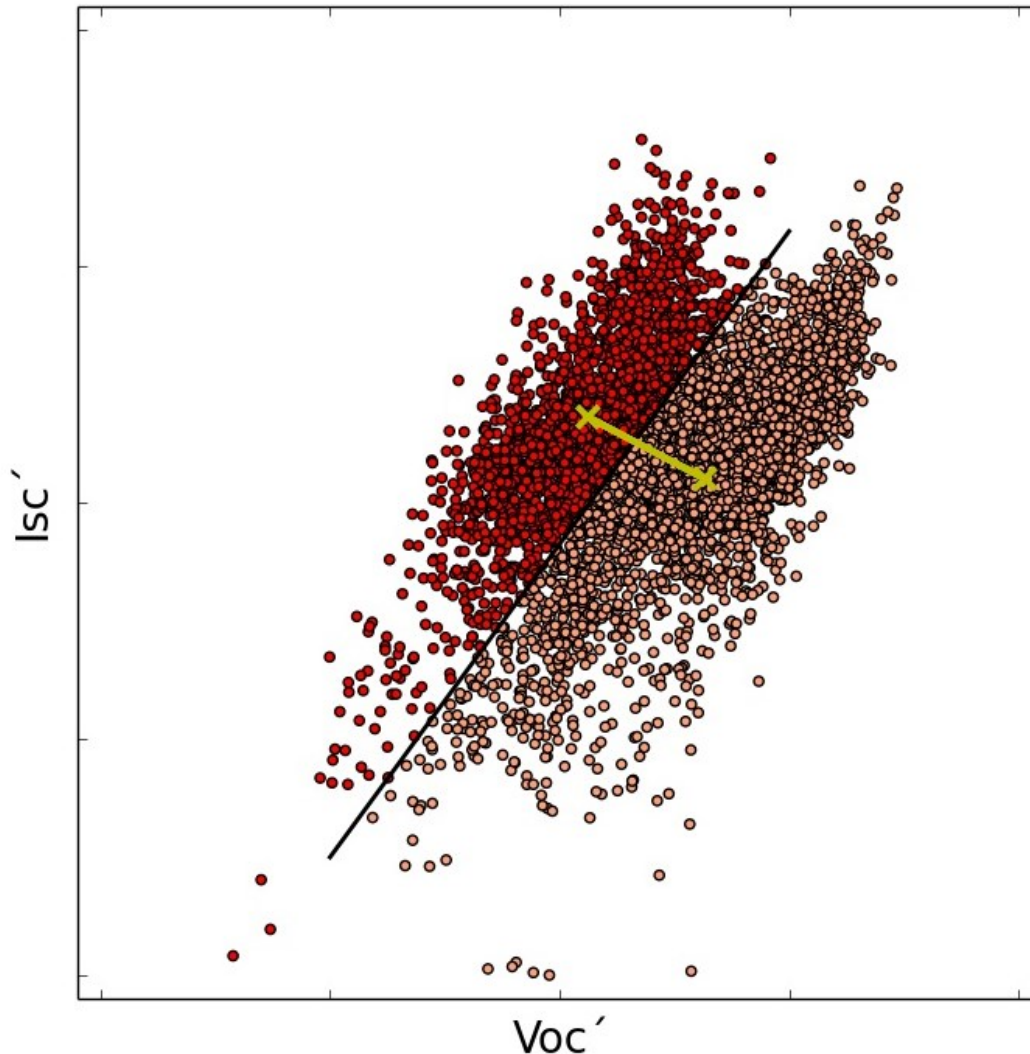


PC1D, can model this sort of Voc/Isc relationship by *varying the lifetime* of the wafer.

The exact slope is providing information on the recombination properties

# Isc vs Voc data

- What about the double distribution in the line 1 data?



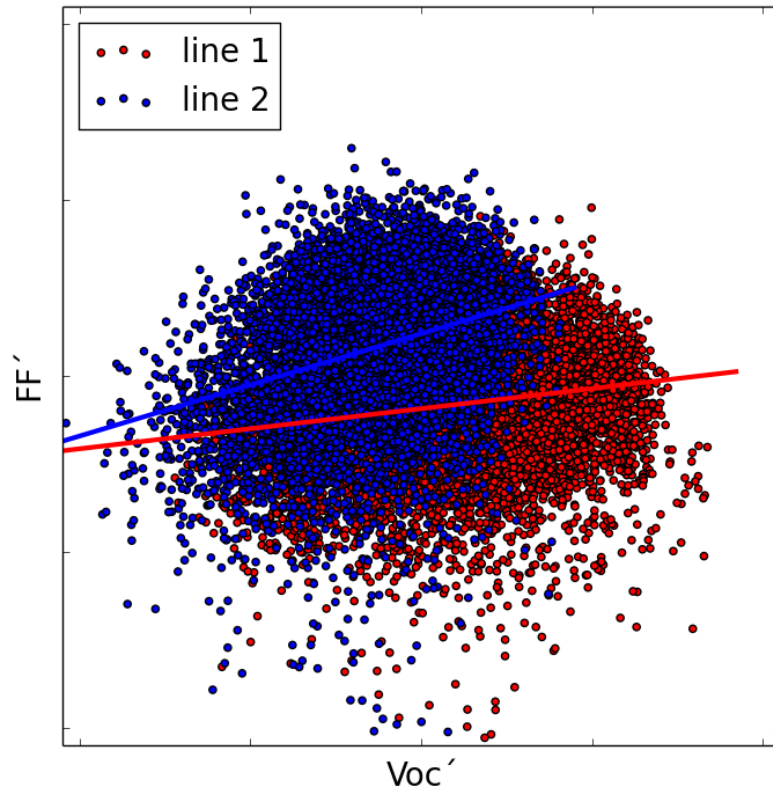
- The data can be split approximately as shown
- The centroid of each data-set calculated and a line plotted between them.
- The angle of this line is between -25 and -30

PC1D models say  
this is the  $V_{oc}$  /  
 $I_{sc}$  relationship  
expected from  
*wafer resistivity  
changes*

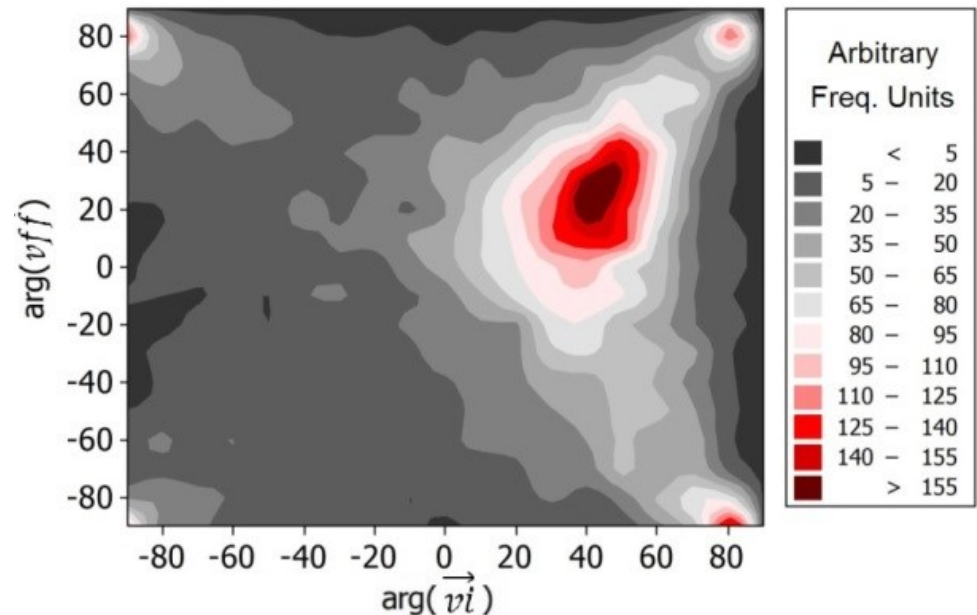
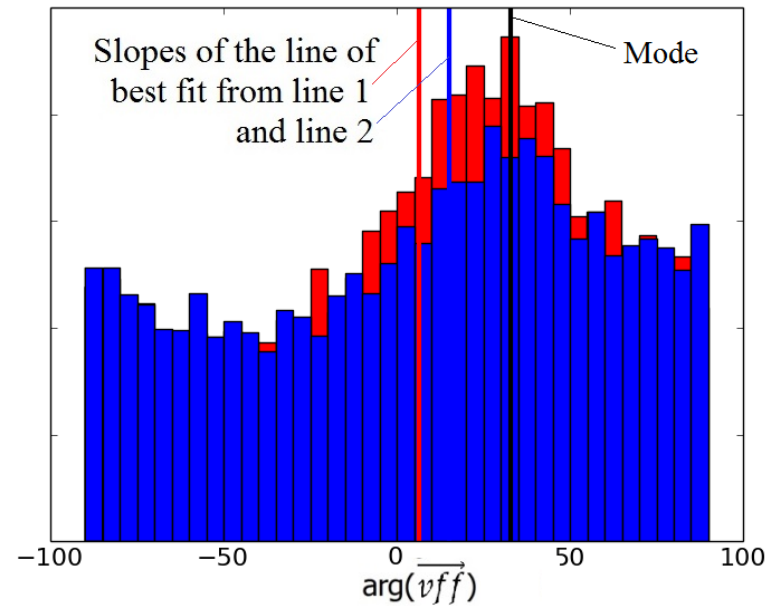


# FF vs Voc data

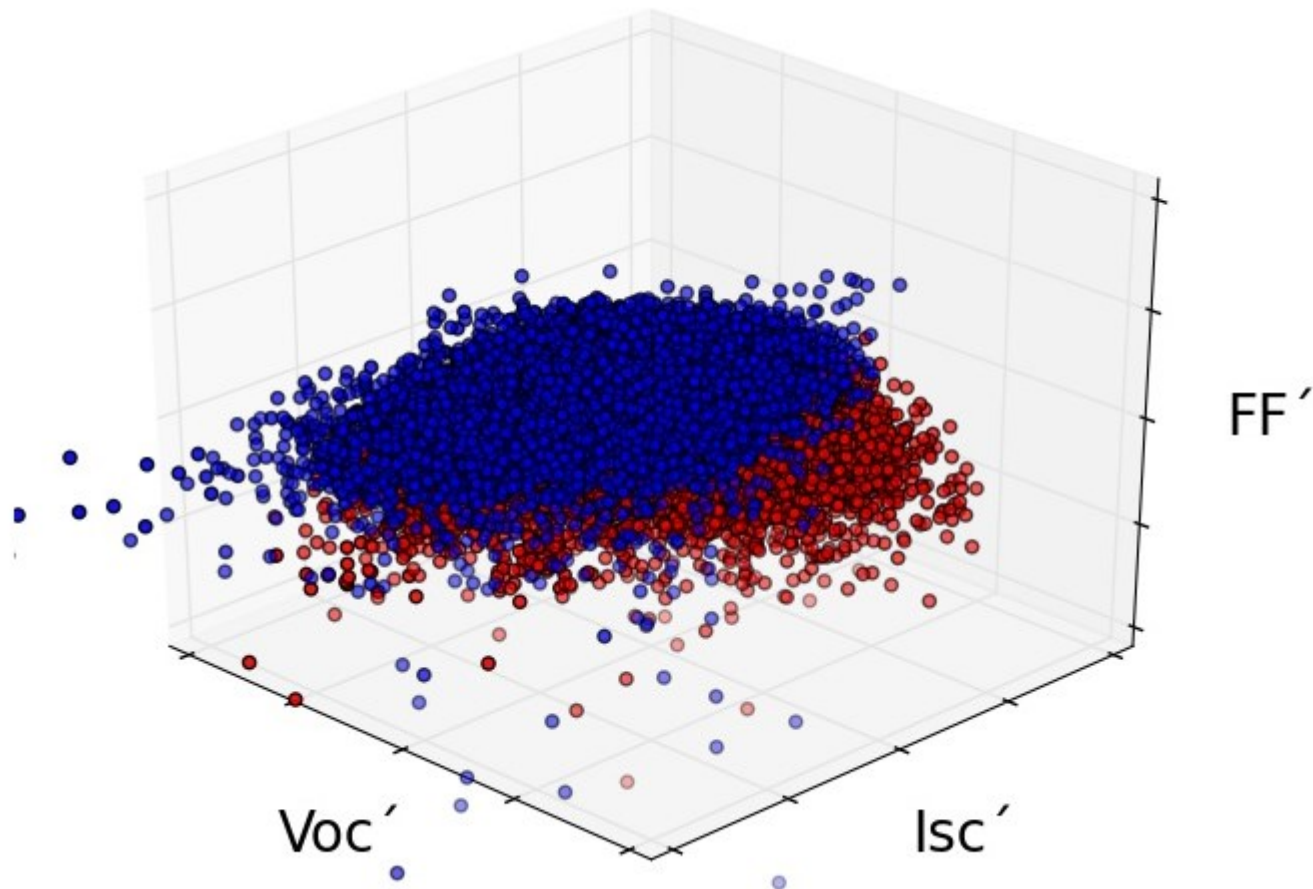
- The same vector analysis can be done for FF / Voc



- Plotting together suggests a common causality.

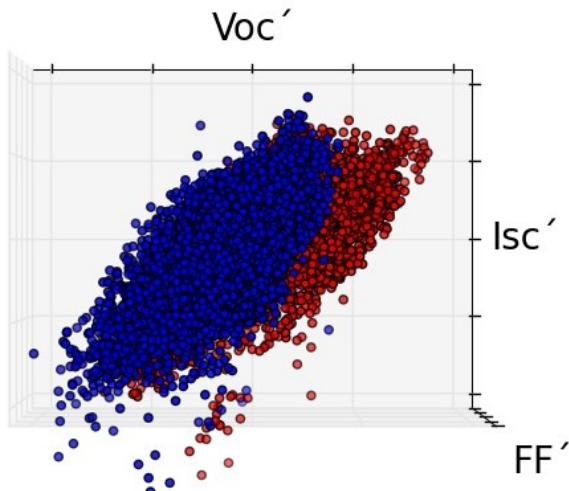


- Consider the cell data in three-dimensional space with wafer lifetime a dominant source of variation

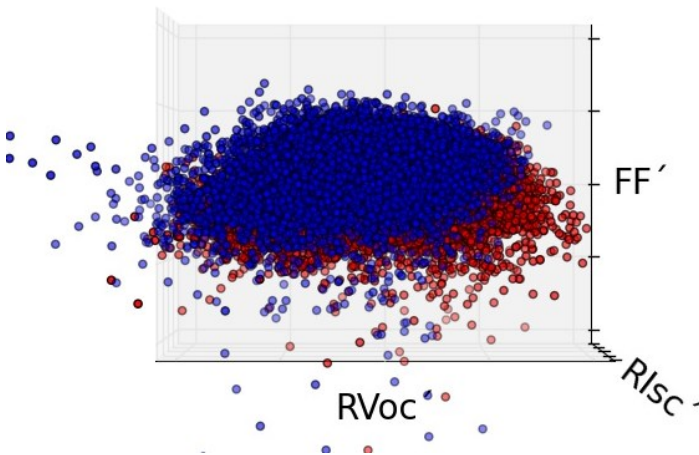
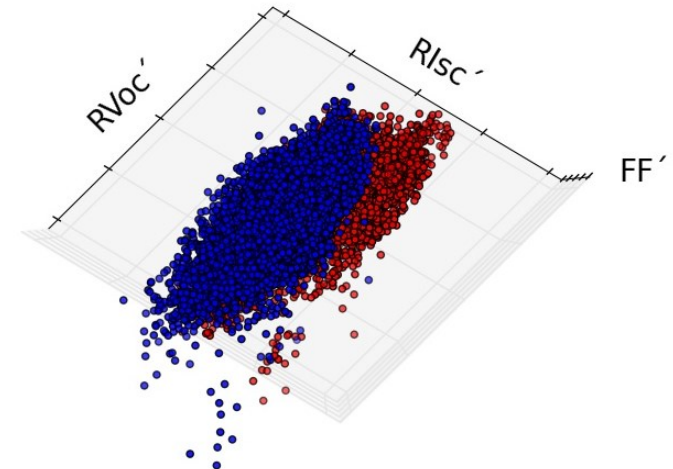


# Axis Rotation

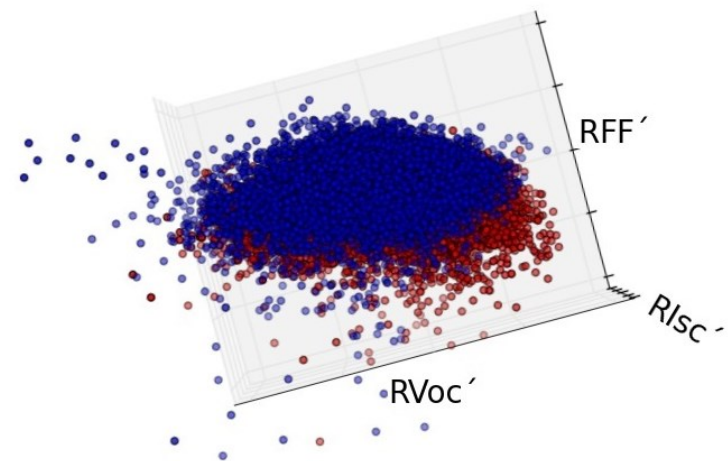
- It is possible to rotate the data axis wrt the cell data to isolate the effects of material variation.

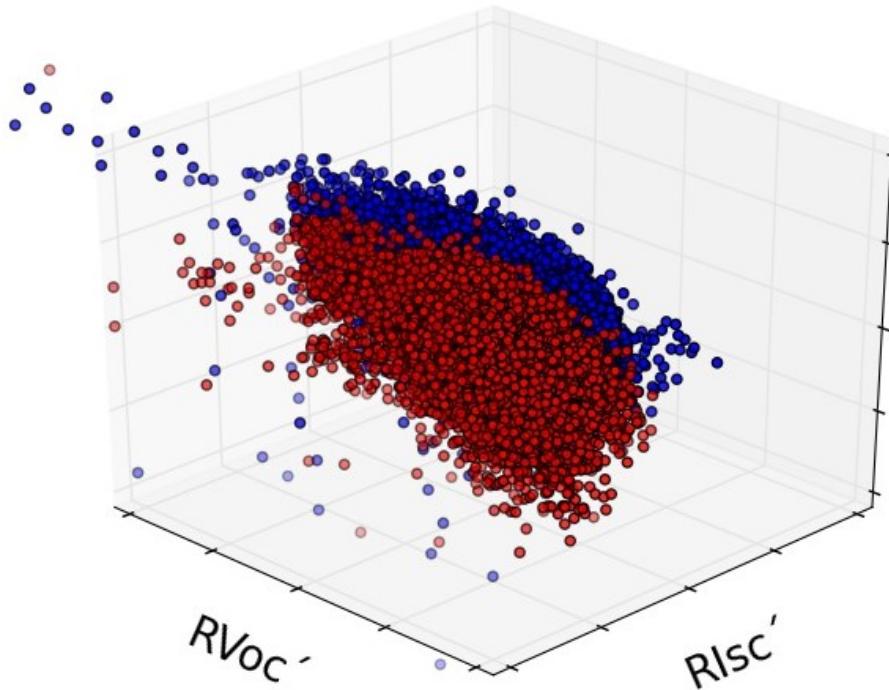


**Rotate  $Voc' /$   
 $Isc'$  Axis**



**Rotate  $FF' /$   
 $Voc'$  Axis**



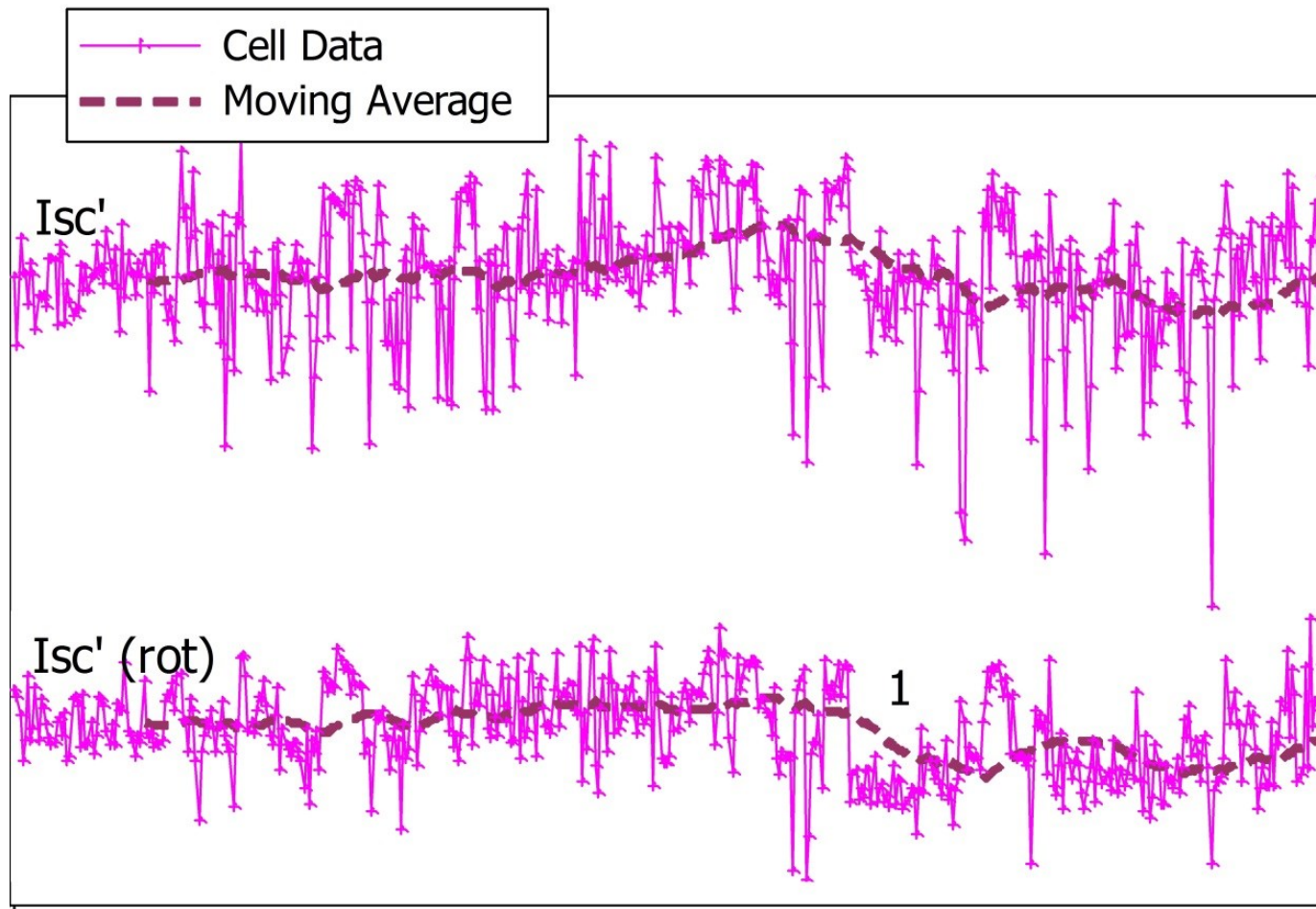


- $RVoc'$  axis now represents material lifetime variation
- $Rlsc'$  axis describes variation in  $Isc'$  unrelated to material
- $RFF'$  axis describes variation in  $FF'$  unrelated to material



# Using Rotated Data

- Undertaking SPC on rotated components means material effects are removed and other process faults are highlighted



## Summary

- Data optimisation is an important part of future PV manufacturing
- Shown here are three basic and important multivariate approaches
  1. Data normalisation to share statistical techniques
  2. Some introductory data manipulation or data mining techniques
  3. Axis rotation to isolate variance
- Large data sets contain information on detailed cell properties

## Future Work

- The precise angles in the  $I_{sc}$  /  $V_{oc}$  and  $FF$  /  $V_{oc}$  relationships tell us about the detailed recombination properties of the cells.
  - This requires further investigation
- Build more extensive statistical models to characterise manufacturing.
  - Statistical models of optimal manufacturing size
  - Models describing optimal data sets for manufacturing